NSN 5962-01-269-1174

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View Online at https://aerobasegroup.com/nsn/5962-01-269-1174
Body Length:
Between 1.435 inches and 1.485 inches
Body Width:
Between 0.515 inches and 0.600 inches
Body Height:
Between 0.140 inches and 0.185 inches
Operating Tempurature Range:
-0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Electrostatic sensitive and ultraviolet erasable and programmable and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.6 volts power source and 14.0 volts power source
Time Rating Per Chacteristic:
250.00 nanoseconds propagation delay time, low to high level output and 250.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Precious Material And Location:
Terminal surfaces option gold
Precious Material:
Gold
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization: Yes - demil/mli

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